UN

ON Semiconductor®

www.onsemi.com

CMOS LSI

OIS/AF Controller & Driver

Overview

LC898123XC is a system LSI integrating an on-chip 32bit DSP, a Flash Memory and peripherals including analog circuits for OIS(Optical Image Stabilizer) /AF(Auto Focus) control and H-bridge and constant current drivers.

Features

- On-chip 32-bit DSP
- Built-in software digital servo filter
- Built-in Gyro filter
- Flash Memory
- 12k Byte Flash memory to store data and DSP program
- Peripherals
- AD converter
 - · 12bit
 - · Input 4ch
 - Equipped with a sample-hold circuit
- DA converter
 - · 8bit
 - · Output 3ch
- Built-in Serial I/F circuit (2-wire Bus) (1MHz)
- Built-in Hall Bias circuit
- Built-in Hall Amp (Gain of Op-amp : $\times 6$, $\times 12$, $\times 50$, $\times 75$, $\times 100$, $\times 150$, $\times 200$)
- Built-in OSC (Oscillator)
 - Typ. 41MHz (with Frequency adjustment function)
- Built-in LDO (Low Drop-Out regulator)
- Digital Gyro I/F for various types of gyro (SPI Bus)
- Motor Driver
 - OIS

Constant current linear driver (×2ch, I_{full}=195mA) H-bridge driver (×2ch, Io max=220mA)

• OP-AF (unidirection)

Constant current linear driver (×1ch, Ifull=135mA)

• OP-AF (bidirection)

Constant current linear driver (×1ch, Ifull=130mA)

- Package
- WLCSP35 (3.39mm × 2.3mm)
- Pb-Free / Halogen Free
- Power Supply Voltage

AD/DA/VGA/LDO/OSC : AVDD30=2.6V to 3.6V
 Digital I/O : DVDD30=2.6V to 3.6V
 Driver : VM=2.6V to 3.6V

• Core Logic : Generation by on-chip LDO

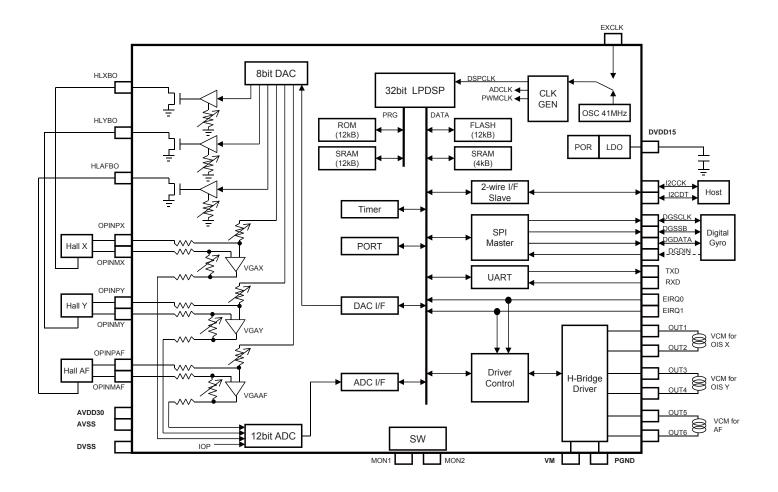
DVDD15=1.5V (typ) output

ORDERING INFORMATION

See detailed ordering and shipping information on page 12 of this data sheet.

WLCSP35 3.39x2.3

Block Diagram

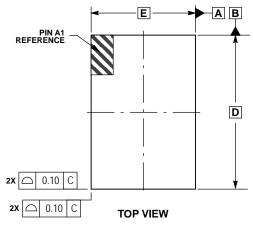


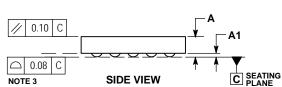
Package Dimensions

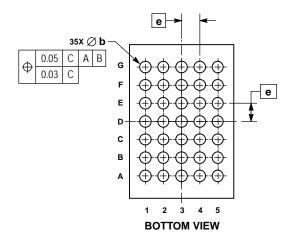
unit: mm

WLCSP35, 3.39x2.3

CASE 567JG **ISSUE O**







NOTES:

- NOTES:

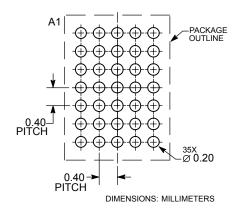
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

	MILLIMETERS				
DIM	MIN	MAX			
Α		0.45			
A1	0.03	0.13			
b	0.15	0.25			
D	3.39	BSC			
E	2.30 BSC				
е	0.40	BSC			

RECOMMENDED SOLDERING FOOTPRINT*

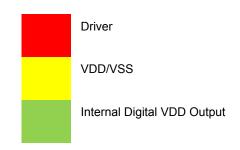


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Pin Assignment

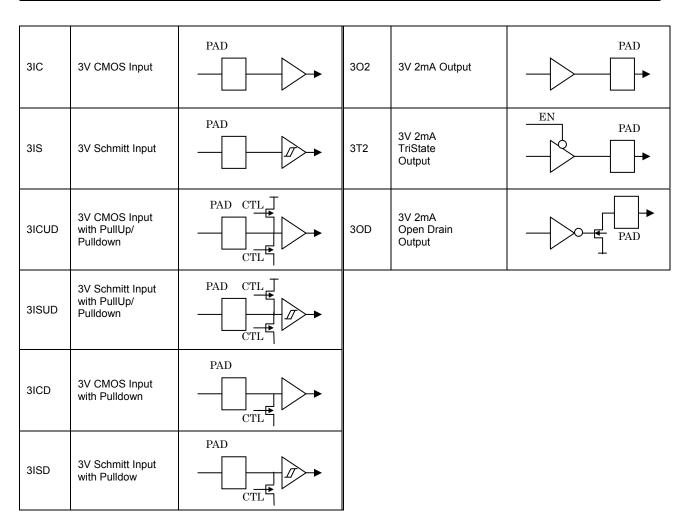
Bottom View

5	OUT5	OUT3	OUT4	PGND	OUT2	OUT1	RXD
4	OUT6	DGDATA	DGSSB	VM	I2CDT	I2CCK	TXD
3	HLAFBO	DGSCLK	DVSS	NC	EXCLK	DGDIN	EIRQ1
2	HLYBO	HLXBO	OPINM AF	OPINMX	OPINMY	EIRQ0	MON2
1	OPINP AF	OPINPX	OPINPY	AVSS	AVDD30	DVDD15	MON1
	G	F	E	D	С	В	А



Pin Description

	I/O	Pin Specification					
1	Input	3IC	3V CMOS Input	3IA	3V Analog Input		
0	Output	3IS	3V CMOS Schmitt Input	3OA	3V Analog Output		
В	Bidirection	3ICUD	3V CMOS Input with PullUp/PullDown				
Р	Power	3ISUD	3V CMOS Schmitt Input with PullUp/PullDown				
		3ICD	3V CMOS Input with PullDown				
		3ISD	3V CMOS Schmitt Input with PullDown				
		302	3V 2mA Output				
		3T2	3V 2mA TriState Output	Z/U/D	HiZ/PullUp/PullDown		
		3OD	3V 2mA Open Drain Output	H/L	HIGH/LOW		



	Pin	I/O	I/O S	рес	Primary Function	Sub Functions	Init
A1	MON1	В	3ICUD	3T2 3OA	(Debugger Data Input)	I2C Data I/O for DAC Monitor Servo Monitor Analog Out Internal Signal Monitor	z
A2	MON2	В	3ICUD	3T2 3OA	(Debugger Data Output)	I2C Data I/O for DAC Monitor Servo Monitor Analog Out Internal Signal Monitor	Z
А3	EIRQ1	В	3ISUD	3T2 3OA	External IRQ External Clock Input	I2C Data I/O for DAC Monitor UART Data Input(RXD) Internal Signal Monitor Servo Monitor Analog Input	z
A4	TXD	В	3ICUD	3T2	UART Data Output	I2C Data I/O for DAC Monitor I2C Data for I2C Master Internal Signal Monitor	Z
A5	RXD	В	3ICUD	3T2	UART Data Input	I2C Data I/O for DAC Monitor I2C Clock for I2C Master Internal Signal Monitor	z
B1	DVDD15	Р			Internal LDO Power Output		-
B2	EIRQ0	В	3ICD	3OD	External IRQ0	I2C Data I/O for DAC Monitor UART Data Output(TXD) Internal Signal Monitor	Z
В3	DGDIN	В	3ICUD	3T2	Digital Gyro Data Input (4 Wired)	I2C Data I/O for DAC Monitor Internal Signal Monitor	U
B4	I2CCK	В	3IS	3OD	I2C Clock	-	Z
B5	OUT1	0		3OA	OIS Driver Output (H-Bridge or Linear)		-
C1	AVDD30	Р			Analog Power (2.6 to 3.6V)		-
C2	OPINMY	ı	3IA		OIS Hall Y Opamp Input Minus		-
СЗ	EXCLK	В	3ISD	3OD	External Clock Input External IRQ1	I2C Data I/O for DAC Monitor Internal Signal Monitor	Z
C4	I2CDT	В	3IS	3OD	I2C Data		Z
C5	OUT2	0		3OA	OIS Driver Output (H-Bridge or Linear)		-
D1	AVSS	Р			Analog GND		-
D2	OPINMX	I	3IA		OIS Hall X Opamp Input Minus		-
D3	NC	-			No Connection		-
	DVSS	Р			Logic GND		-
D4	VM	Р			Driver Power (2.6V to 3.6V)		-
D5	PGND	Р			Driver GND		-

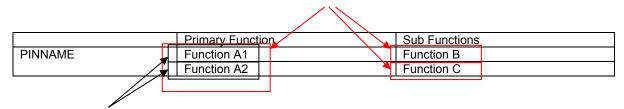
	Pin	I/O	I/O S	рес	Primary Function	Sub Functions	Init
E1	OPINPY	I	3IA		OIS Hall Y Opamp Input Plus		-
E2	OPINMAF	1	3IA		AF Hall OpAmp Input Minus		-
E3	DVSS	Р			Logic GND		-
E4	DGSSB	В	3ICUD	3T2	Digital Gyro I/F Chip Select Input Digital Gyro I/F Chip Select Output	Digital Gyro I/F Chip Select Output Internal Signal Monitor	U
E5	OUT4	0		3OA	OIS Driver Output (H-Bridge or Linear)		-
F1	OPINPX	I	3IA		OIS Hall X Opamp Input Plus		-
F2	HLXBO	0		3OA	OIS Hall X Bias Output		-
F3	DGSCLK	В	3ICUD	3T2	Digital Gyro I/F Clock Input	Digital Gyro Clock Output	U
	DOOOLIK	D	31000	012	Digital Gyro I/F Clock Output	Internal Signal Monitor	Ü
F4	DGDATA	В	3ICUD	3T2	Digital Gyro Data I/F Output	Digital Gyro I/F Data I/O (3 Wired)	U
	DODATA	D	5100	512	(4 Wired)	Internal Signal Monitor	J
F5	OUT3	0		3OA	OIS Driver Output (H-Bridge or Linear)		-
G1	OPINPAF	I	3IA		AF Hall Opamp Input Plus		-
G2	HLYBO	0		3OA	OIS Hall Y Bias Output		-
G3	HLAFBO	0		3OA	AF Hall Bias Output		-
G4	OUT6	0		3OA	AF Driver Output(H-Bridge,Linear)		-
G5	OUT5	0		3OA	AF Driver Output(H-Bridge,Linear)		-

[How to select the function]

The initial function right after reset is set to be "Function A1" in the below table.

You can change the function by CmIOPN, CmMstMode, CmExtClkSel.

One of Function A,B,C... can be selected by CmIOPN [N=0,1,2,...10] register.



DGSSB, DGSCLK: CmMstMode selects A1 or A2. EXCLK, EIRQ1: CmExtClkSel selects A1 or A2.

Electrical Characteristics

Logic

Absolute Maximum Rating at V_{SS} =0V

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage	V _{AD} 30 max	Ta ≤ 25°C	-0.3 to 4.6	V
Input/Output voltage	V _{AI} 30, V _{AO} 30	Ta ≤ 25°C	-0.3 to V _{AD} 30+0.3	V
Input/Output voltage	V _{DI} 30, V _{DO} 30	Ta ≤ 25°C	–0.3 to V _{DD} 30+0.3	V
Storage temperature	Tstg		–55 to 125	°C
Operating temperature	Topr		−30 to 85	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Allowable Operating Ratings at Ta=-30 to 85°C, VSS=0V

3.0V Power Supply (AVDD30)

Parameter	Symbol	Min	Тур	Max	Unit
Power supply voltage	V _{AD} 30	2.6	3.0	3.6	V
Input voltage range	VIN	0	-	3.6	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

D.C. Characteristics at Input/Output V_{SS} = 0V, AV_{DD} =2.6 to 3.6V, Ta =-30 to 85°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	Applicable I/O
High-level input voltage	VIH	CMOS	1.48			V	3IS, 3ISUD, 3ISD
Low-level input voltage	VIL	schmitt			0.37	V	313, 31300, 3130
High-level input voltage	VIH	CMOS	1.40				ale alelib aleb
Low-level input voltage	VIL	supported			0.51	V	3IC, 3ICUD, 3ICD
High-level output voltage	VOH	IOH=-2mA	AV _{DD} 30 -0.4			V	3O2, 3T2
Low-level output voltage	VOL	IOL= 2mA			0.4	٧	502, 512
Low-level output voltage	VOL	IOL= 2mA			0.2	>	3OD
Analog input voltage	VAI		AVSS		AV _{DD} 30	٧	3IA
PullUp resistor	Rup		50		200	ΚΩ	3ICUD, 3ISUD
PullDown resistor	Rdn		50		220	ΚΩ	3ICUD, 3ISUD, 3ISD, 3ICD

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Non-volatile Memory Characteristics

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Endurance	EN				1000	Cycles
Data retention	RT		10			Years

Driver

Absolute Maximum Ratings

Parameter	Symbol	Condition	Ratings	Symbol
Power supply voltage	VM max		4.6	V
Output peak current	lopeak	OUT1 to 4 T ≤ 10ms, ON-duty ≤ 20% OUT5, OUT6 t ≤ 10ms, ON-duty ≤ 20%	300 200	mA mA
Output continuous current	Iomax	OUT1 to 4	220	mA
	IOIIIAX	OUT5, OUT6	150	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Allowable Operating Range

Parameter	Symbol	Condition	Ratings	Symbol
Ambient temperature	Topg		−30 to +85	°C
Power supply voltage	VM		2.6 to 3.6	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

H-Bridge Driver Output Characteristics at Ta=25°C, AV_{DD}30=VM=3.0V

Parameter	Symbol	Condition	Ratings (Ω)	Symbol
Output ON resistance	Ronu	lo=220mA (Pch)	1.1	Ω
OUT1 to OUT4	Rond	Io=220mA (Nch)	1.3(*)	Ω
Output ON resistance	Ronu	Io=150mA (Pch)	1.5	Ω
OUT5, OUT6	Rond	lo=150mA (Nch)	1.4(*)	Ω

(*) include Constant current detect resistance

Constant Current Driver Output at Ta=25°C, AV_{DD}30=VM=2.8V

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Output Current OUT1 to OUT4		OIS_DA[10:0]=7FFh OIS_DB[10:0]=7FFh	175.5	195.0	214.5	mA
Output Current OUT5, OUT6	I _{full}	OP-AF(unidirection) AF_D[9:0]=3FFh	121.5	135.0	148.5	mA
		OP-AF(bidirection) AF_D[9:0]=3FFh	117.0	130.0	143.0	mA
Compliance Voltage OUT1 to OUT4			0.4			V
Compliance Voltage	Vcomp	OP-AF(unidirection)	0.4			V
OUT5,OUT6		OP-AF(bidirection)	0.5			V

Total output current is less than 500mA.

OP-AF(unidirection)

VCM registance (Rvcm) = $(VM-Vcomp)/Io [\Omega]$

OP-AF(bidirection)/OIS

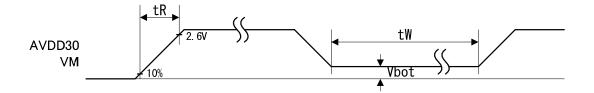
VCM registance (Rvcm) = $(VM-(Ronu\times Io+Vcomp))/Io[\Omega]$

Output ON resistance (Ron) = $VM/Io - Rvcm [\Omega]$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC Characteristics

Power Sequence



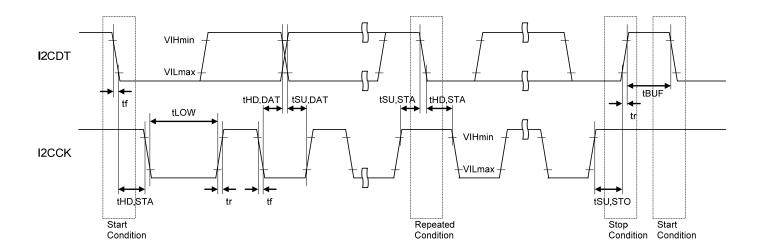
Item	Symbol	Min	Тур	Max	Units
Rise time	tR			5	ms
Wait time	tW	100			ms
Bottom Voltage	Vbot			0.2	V

Don't care about injection order between AV_{DD}30 and VM. I2CDT, I2CCK, EXCLK and EIRQ0 tolerate 3V input at the time of power off.

The data in the flash memory may be destroyed if you do not keep specifications. And it is forbidden to power off during flash access. The data in the flash memory may be destroyed.

2-wire serial Interface Timing

The communication protocol is compatible with I²C (Fast mode Plus). This circuit has clock stretch function.



I²C interface timing definition

Item	Symbol	Pin name	Min	Тур	Max	Units
SCL clock frequency	Fscl	I2CCK			1000	kHz
START condition hold time	tHD,STA	I2CCK I2CDT	0.26			μS
SCL clock Low period	tLOW	I2CCK	0.5			μS
SCL clock High period	tHIGH	I2CCK	0.26			μS
Setup time for repetition START condition	tSU,STA	I2CCK I2CDT	0.26			μS
Data hold time	tHD,DAT	I2CCK I2CDT	0 (*1)		0.9	μS
Data setup time	tSU,DAT	I2CCK I2CDT	50			ns
SDA, SCL rising time	tr	I2CCK I2CDT			120	ns
SDA, SCL falling time	tf	I2CCK I2CDT			120	ns
STOP condition setup time	tSU,STO	I2CCK I2CDT	0.26			μS
Bus free time between STOP and START	tBUF	I2CCK I2CDT	0.5			μS

(*1) Although the I²C specification defines a condition that 300 ns of hold time is required internally, LC898123 is designed for a condition with typ. 100 ns of hold time. If SDA signal is unstable around falling point of SCL signal, please implement an appropriate treatment on board, such as inserting a resistor.

ORDERING INFORMATION

Device	Package	Shipping (Qty / Packing)
LC898123XC-VH	WLCSP35, 3.39x2.3 (Pb-Free / Halogen Free)	4000 / Tape & Reel

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent re